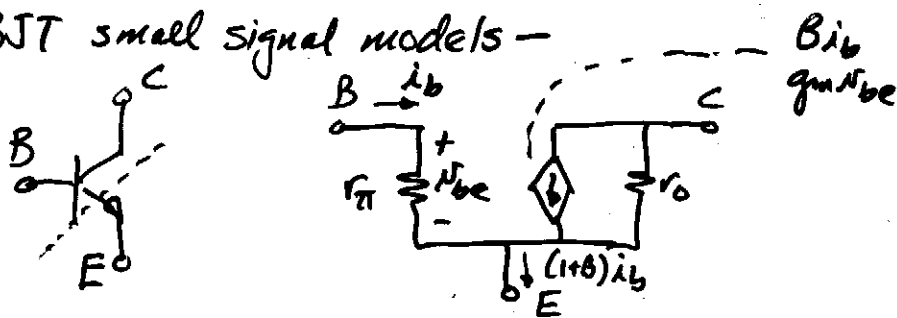


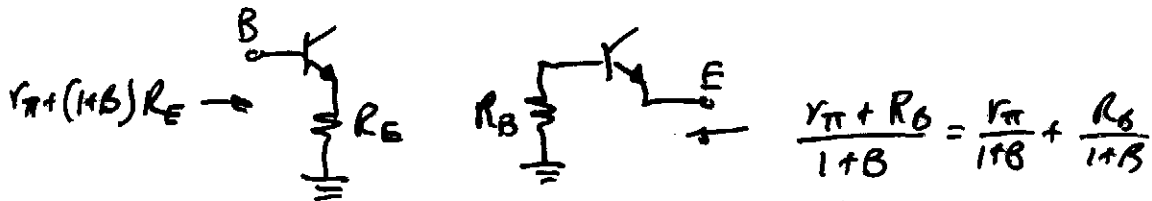
Summary of Chapter 13

- Common source and common emitter amplifier
- Midband small-signal (ac) performance/modeling
- Find small-signal model parameters as a function of operating (quiescent) point. (DC conditions)
- Convert from schematic to small-signal model (short power supplies, replace $C = \infty$ with shorts, remove dc current sources)
- Be able to find r_{in} , R_{out} , $\frac{v_{out}}{v_{in}}$, and $\frac{i_{out}}{i_{in}}$.

BJT small signal models -



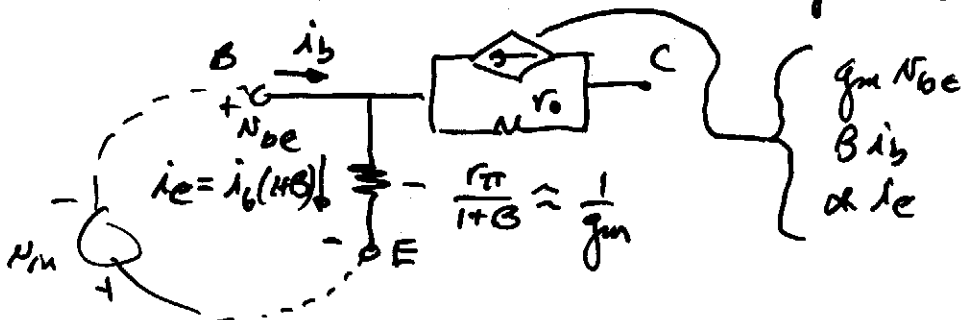
E-B Impedance Reflection -



$$\frac{r_{\pi} + R_B}{1 + \beta} = \frac{r_{\pi}}{1 + \beta} + \frac{R_B}{1 + \beta}$$

$$\approx \frac{1}{g_m} + \frac{R_B}{1 + \beta}$$

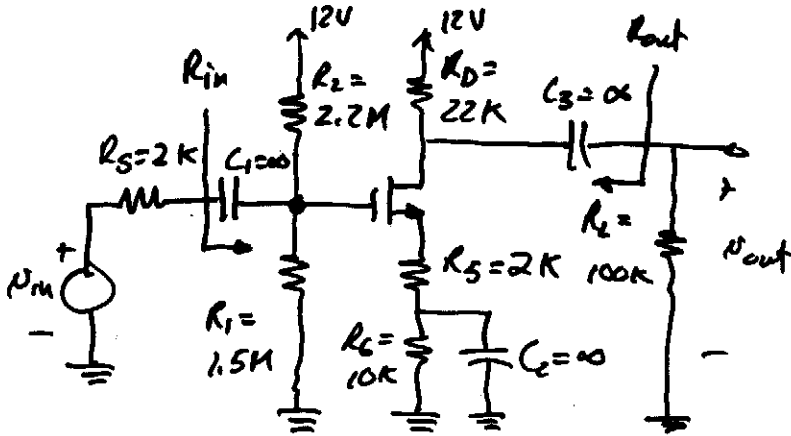
Tee Model



- $g_m v_{be}$
- βi_b
- αi_e

Chapter 11 - CC (CD), CB (CG) and Common Nothing

Example - Common Nothing ~~CB~~ MOSFET



Find $\frac{v_{out}}{v_{in}}$, R_{in} , and R_{out}
 if $K'_N = 500 \mu A/V^2$,
 $V_{TN} = 1V$ $\lambda = 0.02 V^{-1}$

1.) Solve for the dc operating point (I_D , V_{DS} , V_{GS}).

Solving the dc circuit gives $I_D = 241 \mu A$, $V_{DS} = 3.81V$,
 and $V_{GS} = 1.922V$.

$$\left. \begin{aligned} V_{GG} &= \frac{R_2}{R_1 + R_2} V_{DD} + V_{GS} + I_D (R_S + R_C) \\ I_D &= K'_N (V_{GS} - V_{TN})^2 \end{aligned} \right\}$$

2.) $g_m = \sqrt{2 K'_N I_D (1 + \lambda V_{DS})} = \sqrt{2 \cdot 500 \cdot 241 (1 + \frac{3.81}{30})} = 509 \mu S$

$r_{ds} = r_o = \frac{1}{\lambda} + \frac{V_{DS}}{I_D} = \frac{50 + 3.81}{241} MS = 223 k\Omega$

